# BLC9G20XS-550AVT

**Power LDMOS transistor**

**Rev. 3 — 24 November 2017**

AMPLEON

**Product data sheet**

## 1. Product profile

### 1.1 General description

550 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 1805 MHz to 1880 MHz.

**Table 1. Typical performance**

*Typical RF performance at $T_{case}$ = 25 °C in an asymmetrical Doherty production test circuit. $V_{DS}$ = 28 V; $I_{Dq}$ = 1100 mA (main); $V_{GS(amp)peak}$ = 0.7 V, unless otherwise specified.*

| Test signal | f | $V_{DS}$ | $P_{L(AV)}$ | $G_p$ | $\eta_D$ | ACPR |
|---|---|---|---|---|---|---|
| | (MHz) | (V) | (W) | (dB) | (%) | (dBc) |
| 1-carrier W-CDMA | 1805 to 1880 | 28 | 85 | 15.4 | 44.5 | –34 [1] |

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

### 1.2 Features and benefits

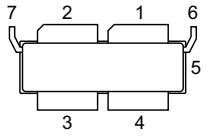
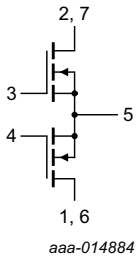
- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1880 MHz frequency range

## 2. Pinning information

**Table 2. Pinning**

| Pin | Description | Simplified outline | Graphic symbol |
|---|---|---|---|
| 1 | drain2 (peak) |  |  |
| 2 | drain1 (main) | | |
| 3 | gate1 (main) | | |
| 4 | gate2 (peak) | | |
| 5 | source [1] | | |
| 6 | video decoupling (peak) | | |
| 7 | video decoupling (main) | | |



[1] Connected to flange.

## 3. Ordering information

**Table 3. Ordering information**

| Type number | Package | | |
|---|---|---|---|
| | Name | Description | Version |
| BLC9G20XS-550AVT | - | air cavity plastic earless flanged package; 6 leads | SOT1258-4 |

## 4. Limiting values

**Table 4. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---|---|---|---|---|---|
| $V_{DS}$ | drain-source voltage | | - | 65 | V |
| $V_{GS(amp)main}$ | main amplifier gate-source voltage | | –6 | +13 | V |
| $V_{GS(amp)peak}$ | peak amplifier gate-source voltage | | –6 | +13 | V |
| $T_{stg}$ | storage temperature | | –65 | +150 | °C |
| $T_j$ | junction temperature | [1] | - | 225 | °C |
| $T_{case}$ | case temperature | operating [1] | –40 | +125 | °C |

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

## 5. Thermal characteristics

**Table 5. Thermal characteristics**

| Symbol | Parameter | Conditions | Typ | Unit |
|---|---|---|---|---|
| $R_{th(j-c)}$ | thermal resistance from junction to case | $V_{DS}$ = 28 V; $I_{Dq}$ = 1100 mA (main); $V_{GS(amp)peak}$ = 0,5 V; $T_{case}$ = 80 °C | | |
| | | $P_L$ = 85 W | 0.27 | k/W |
| | | $P_L$ = 110 W | 0.27 | k/W |


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# 6. Characteristics

**Table 6. DC characteristics**

*$T_j$ = 25 °C unless otherwise specified.*

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| **Main device** | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS}$ = 0 V; $I_D$ = 2.2 mA | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $V_{DS}$ = 10 V; $I_D$ = 220 mA | 1.5 | 2.0 | 2.5 | V |
| $V_{GSq}$ | gate-source quiescent voltage | $V_{DS}$ = 28 V; $I_D$ = 1000 mA | 1.65 | 2.15 | 2.65 | V |
| $I_{DSS}$ | drain leakage current | $V_{GS}$ = 0 V; $V_{DS}$ = 32 V | - | - | 2.8 | µA |
| $I_{DSX}$ | drain cut-off current | $V_{GS}$ = $V_{GS(th)}$ + 3.75 V | - | 40 | - | A |
| $I_{GSS}$ | gate leakage current | $V_{GS}$ = 11 V; $V_{DS}$ = 0 V | - | - | 280 | nA |
| $g_{fs}$ | forward transconductance | $V_{DS}$ = 10 V; $I_D$ = 11 A | - | 14.5 | - | S |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS}$ = $V_{GS(th)}$ + 3.75 V; $I_D$ = 7.7 A | - | 69 | 112 | mΩ |
| **Peak device** | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS}$ = 0 V; $I_D$ = 3.6 mA | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $V_{DS}$ = 10 V; $I_D$ = 360 mA | 1.5 | 2.0 | 2.5 | V |
| $V_{GSq}$ | gate-source quiescent voltage | $V_{DS}$ = 28 V; $I_D$ = 1800 mA | 1.65 | 2.15 | 2.65 | V |
| $I_{DSS}$ | drain leakage current | $V_{GS}$ = 0 V; $V_{DS}$ = 32 V | - | - | 2.8 | µA |
| $I_{DSX}$ | drain cut-off current | $V_{GS}$ = $V_{GS(th)}$ + 3.75 V | - | 65 | - | A |
| $I_{GSS}$ | gate leakage current | $V_{GS}$ = 11 V; $V_{DS}$ = 0 V | - | - | 280 | nA |
| $g_{fs}$ | forward transconductance | $V_{DS}$ = 10 V; $I_D$ = 18 A | - | 23 | - | S |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS}$ = $V_{GS(th)}$ + 3.75 V; $I_D$ = 12.6 A | - | 44 | 72 | mΩ |

**Table 7. RF characteristics**

*Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH; $f_1$ =1807.5 MHz; $f_2$ = 1877.5 MHz; RF performance at $V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA (main); $V_{GS(amp)peak}$ = 0.7 V; $T_{case}$ = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 1805 MHz to 1880 MHz.*

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $G_p$ | power gain | $P_{L(AV)}$ = 85 W | 14.6 | 15.4 | - | dB |
| $RL_{in}$ | input return loss | $P_{L(AV)}$ = 85 W | - | −15 | −10 | dB |
| $\eta_D$ | drain efficiency | $P_{L(AV)}$ = 85 W | 40.5 | 44.5 | - | % |
| ACPR | adjacent channel power ratio | $P_{L(AV)}$ = 85 W | - | −34 | −29 | dBc |

**Table 8. RF characteristics**

*Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH; f = 1877.5 MHz; RF performance at $V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA (main); $V_{GS(amp)peak}$ = 0.7 V; $T_{case}$ = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at a frequency of 1880 MHz.*

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $PAR_O$ | output peak-to-average ratio | $P_{L(AV)}$ = 120 W | 6.4 | 7.0 | - | dB |
| $P_{L(M)}$ | peak output power | $P_{L(AV)}$ = 120 W | 492 | 580 | - | W |


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# 7. Test information

## 7.1 Ruggedness in Doherty operation

The BLC9G20XS-550AVT is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.7 V; f = 1807.5 MHz; $P_L$ = 174 W (5 dB OBO); 100 % clipping.

## 7.2 Impedance information

**Table 9. Typical impedance of main device**

*Measured load-pull data of main device; $I_{Dq}$ = 1100 mA (main); $V_{DS}$ = 28 V; pulsed CW ($t_p$ = 100 $\mu$s; $\delta$ = 10 %).*

| f | $Z_S$ [1] | $Z_L$ [1] | $P_L$ [2] | $\eta_D$ [2] | $G_p$ [2] |
|---|---|---|---|---|---|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| **Maximum power load** | | | | | |
| 1805 | 1.7 – j6.1 | 1.4 – j3.5 | 275 | 58.0 | 18.5 |
| 1840 | 2.3 – j6.6 | 1.5 – j3.4 | 270 | 61.2 | 19.3 |
| 1880 | 3.1 – j6.9 | 1.5 – j3.0 | 240 | 61.4 | 20.2 |
| **Maximum drain efficiency load** | | | | | |
| 1805 | 1.7 – j6.1 | 2.2 – j2.3 | 210 | 67.8 | 20.8 |
| 1840 | 2.3 – j6.6 | 2.2 – j2.3 | 200 | 67.2 | 21.2 |
| 1880 | 3.1 – j6.9 | 2.0 – j2.6 | 210 | 65.7 | 21.0 |

[1] $Z_S$ and $Z_L$ defined in Figure 1.

[2] At 3 dB gain compression.


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**Table 10. Typical impedance of peak device**

*Measured load-pull data of peak device; $I_{Dq}$ = 2200 mA (peak); $V_{DS}$ = 28 V; pulsed CW ($t_p$ = 100 μs; $\delta$ = 10 %).*

| f | $Z_S$ [1] | $Z_L$ [1] | $P_L$ [2] | $\eta_D$ [2] | $G_p$ [2] |
|---|---|---|---|---|---|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| **Maximum power load** | | | | | |
| 1805 | 1.7 – j6.1 | 1.2 – j3.5 | 425 | 58.2 | 18.0 |
| 1840 | 2.4 – j6.6 | 1.2 – j3.5 | 415 | 57.9 | 18.3 |
| 1880 | 3.4 – j7.1 | 1.4 – j3.6 | 405 | 59.1 | 18.6 |
| **Maximum drain efficiency load** | | | | | |
| 1805 | 1.7 – j6.1 | 1.8 – j2.3 | 290 | 65.8 | 20.3 |
| 1840 | 2.4 – j6.6 | 1.6 – j2.6 | 320 | 65.1 | 20.1 |
| 1880 | 3.4 – j7.1 | 1.8 – j2.5 | 285 | 64.6 | 20.4 |

[1] $Z_S$ and $Z_L$ defined in Figure 1.

[2] At 3 dB gain compression.

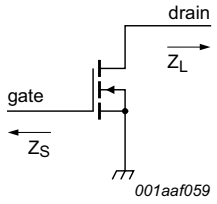



**Fig 1. Definition of transistor impedance**

## 7.3 Recommended impedances for Doherty design

**Table 11. Typical impedance of main at 1 : 1 load**

*Measured load-pull data of main device; $I_{Dq}$ = 1100 mA (main); $V_{DS}$ = 28 V; pulsed CW ($t_p$ = 100 μs; $\delta$ = 10 %).*

| f | $Z_S$ [1] | $Z_L$ [1] | $P_{L(3dB)}$ [2] | $\eta_D$ [2] | $G_p$ [2] |
|---|---|---|---|---|---|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| 1805 | 1.6 – j6.1 | 1.7 – j3.7 | 245 | 39.0 | 19.2 |
| 1840 | 1.9 – j6.8 | 1.7 – j3.3 | 250 | 39.8 | 19.5 |
| 1880 | 2.8 – j7.5 | 1.7 – j2.8 | 235 | 42.0 | 20.3 |

[1] $Z_S$ and $Z_L$ defined in Figure 1.

[2] At $P_{L(AV)}$ = 85 W.


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**Table 12. Typical impedance of main device at 1 : 2.5 load**

*Measured load-pull data of main device; $I_{Dq}$ = 1100 mA (main); $V_{DS}$ = 28 V; pulsed CW ($t_p$ = 100 μs; $\delta$ = 10 %).*

| f | $Z_S$ [1] | $Z_L$ [1] | $P_{L(3dB)}$ [2] | $\eta_D$ [2] | $G_p$ [2] |
|---|---|---|---|---|---|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| 1805 | 1.6 – j6.1 | 4.3 – j3.2 | 145 | 53.2 | 21.7 |
| 1840 | 1.9 – j6.8 | 4.2 – j2.9 | 145 | 51.7 | 21.7 |
| 1880 | 2.8 – j7.5 | 4.2 – j2.6 | 140 | 50.4 | 22.3 |

[1] $Z_S$ and $Z_L$ defined in Figure 1.

[2] At $P_{L(AV)}$ = 85 W.

**Table 13. Typical impedance of peak device at 1 : 1 load**

*Measured load-pull data of peak device; $I_{Dq}$ = 2200 mA (peak); $V_{DS}$ = 28 V; pulsed CW ($t_p$ = 100 μs; $\delta$ = 10 %).*

| f | $Z_S$ [1] | $Z_L$ [1] | $P_{L(3dB)}$ [2] | $\eta_D$ [2] | $G_p$ [2] |
|---|---|---|---|---|---|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| 1805 | 1.5 – j5.9 | 1.8 – j4.2 | 340 | 33.1 | 18.2 |
| 1840 | 1.9 – j6.3 | 1.7 – j3.9 | 350 | 33.8 | 18.7 |
| 1880 | 2.2 – j7.1 | 1.7 – j3.7 | 320 | 35.4 | 19.1 |

[1] $Z_S$ and $Z_L$ defined in Figure 1.

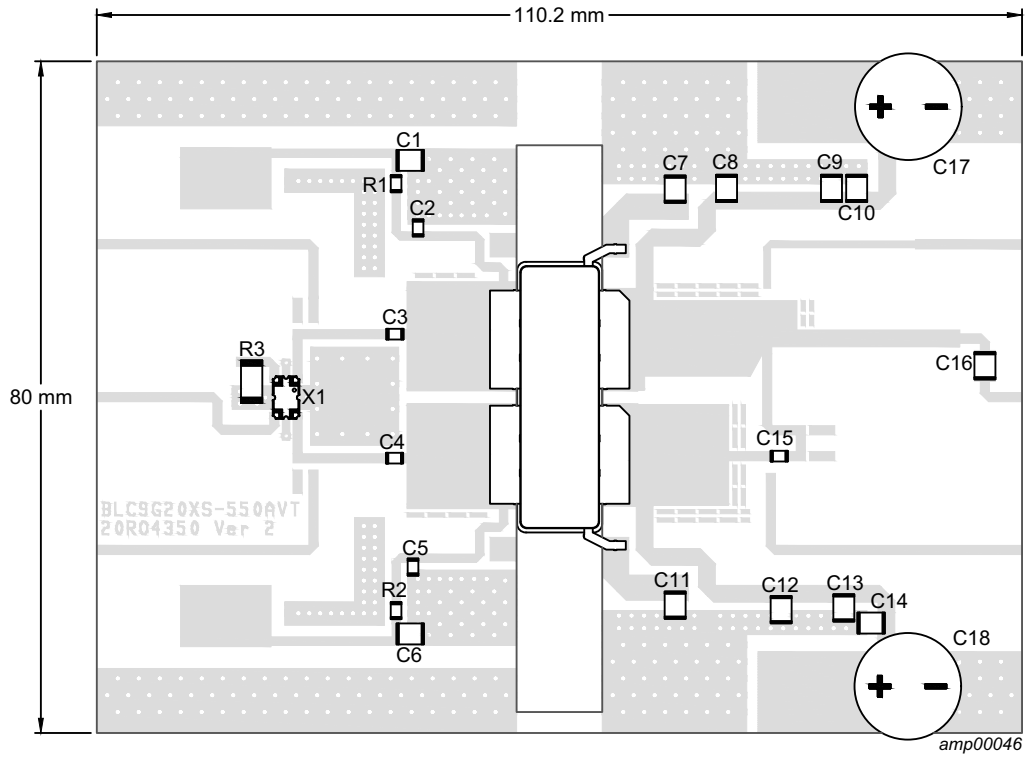
[2] At $P_{L(AV)}$ = 85 W.

**Table 14. Off-state impedances of peak device**

| f | $Z_{off}$ |
|---|---|
| (MHz) | (Ω) |
| 1805 | 2.2 – j3.5 |
| 1840 | 1.1 – j1.7 |
| 1880 | 0.7 – j0.8 |


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## 7.4 Test circuit




Printed-Circuit Board (PCB): Rogers 4350B: $\varepsilon_r$ = 3.66; thickness = 0.635 mm; thickness copper plating = 70 μm. See Table 15 for a list of components.

**Fig 2. Component layout**

**Table 15. List of components**

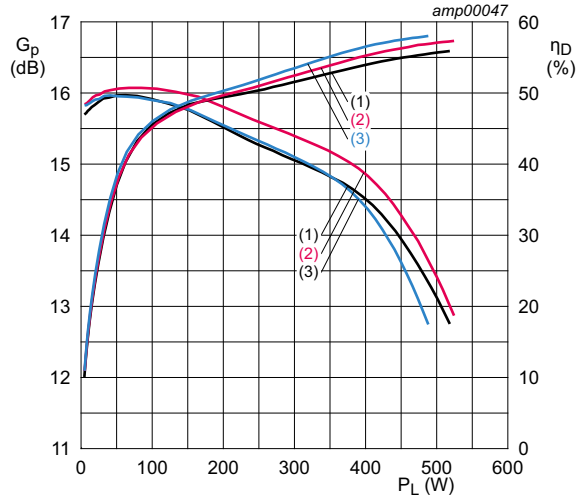
*See Figure 2 for component layout.*

| Component | Description | Value | Remarks |
|---|---|---|---|
| C1, C6, C7, C9, C10, C11, C13, C14 | multilayer ceramic chip capacitor | 4.7 μF, 50 V | Murata GRM32ER71H475KA88L |
| C2, C3, C4, C5 | multilayer ceramic chip capacitor | 20 pF | ATC 100A |
| C8, C12 | multilayer ceramic chip capacitor | 20 pF | ATC 100B |
| C15 | multilayer ceramic chip capacitor | 10 pF | ATC 100A |
| C16 | multilayer ceramic chip capacitor | 10 pF | ATC 100B |
| C17, C18 | electrolytic capacitor | 470 μF, 63 V | |
| R1, R2 | resistor | 2.00 Ω, 1 % | SMD 0805 |
| R3 | resistor | 50 Ω, 25 W | Anaren C16A50Z4 |
| X1 | hybrid coupler | 2 dB, 90° | Anaren Xinger III, X3C20F1-02S |


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## 7.5 Graphical data

### 7.5.1 Pulsed CW



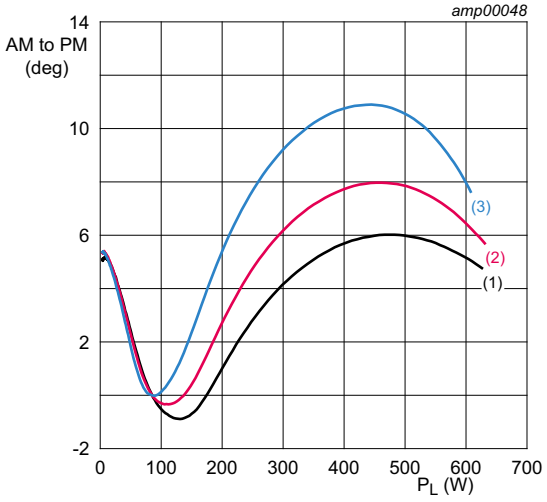

$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V; $t_p$ = 100µs; $\delta$ = 10 %.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 3. Power gain and drain efficiency as function of output power; typical values**




$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

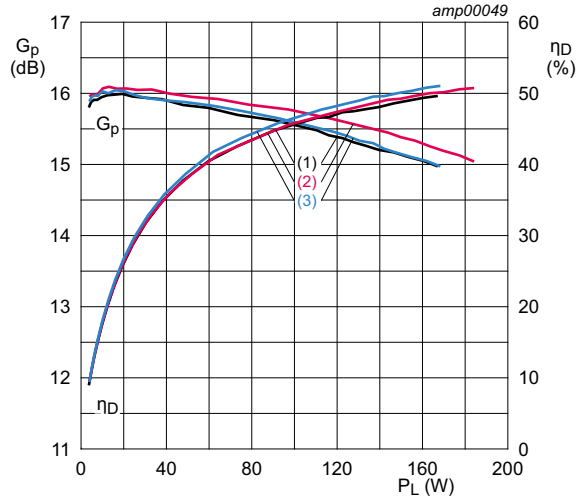
(3) f = 1880 MHz

**Fig 4. Normalized AM to PM as a function of output power; typical values**


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### 7.5.2 1-Carrier W-CDMA

PAR = 9.6 dB per carrier at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (100 % clipping).



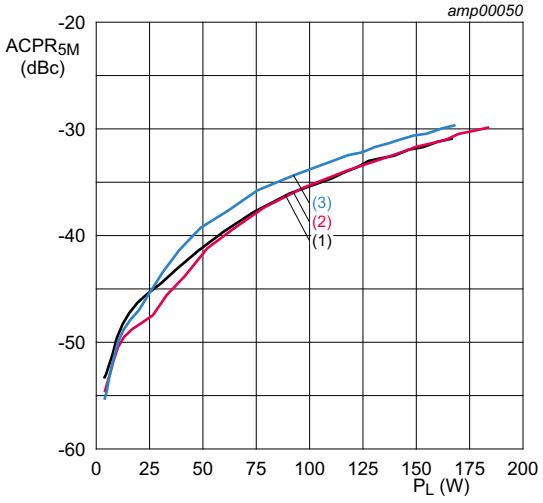

$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 5. Power gain and drain efficiency as function of output power; typical values**



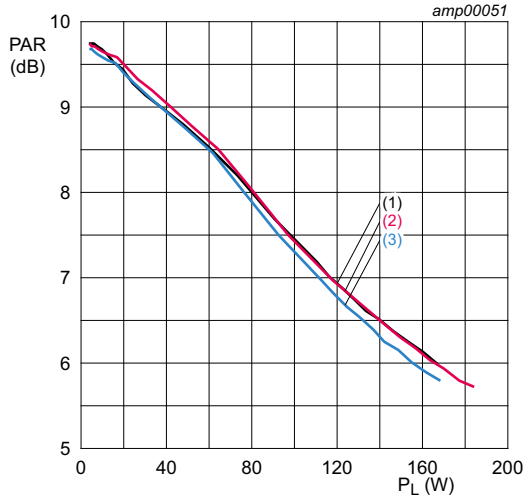

$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values**



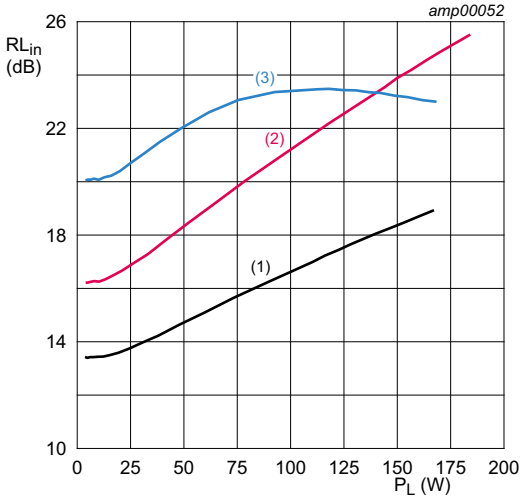

$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 7. Peak-to-average power ratio as a function of output power; typical values**




$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

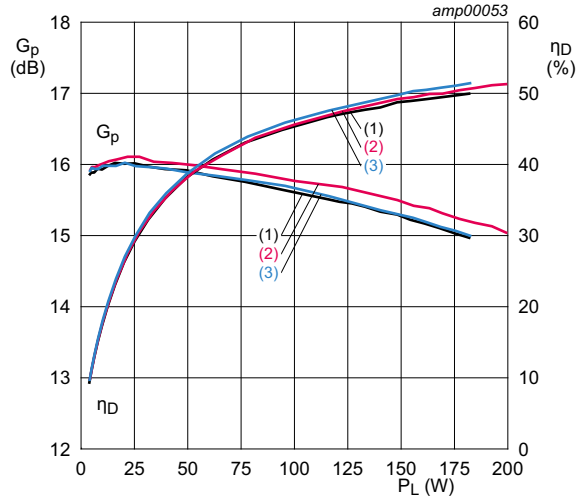
(3) f = 1880 MHz

**Fig 8. Input return loss as a function of output power; typical values**


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### 7.5.3 2-Carrier W-CDMA

PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (46 % clipping).



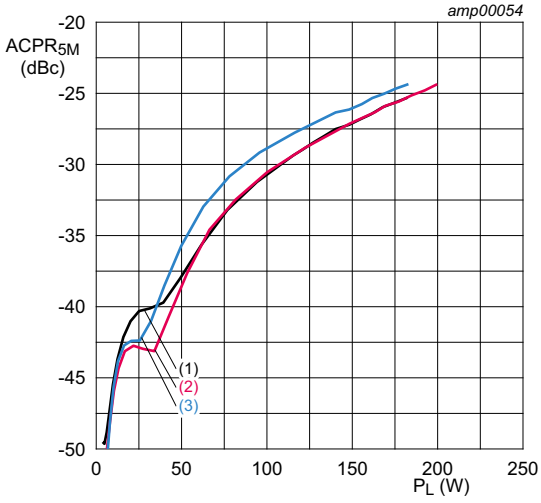

$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 9. Power gain and drain efficiency as function of output power; typical values**



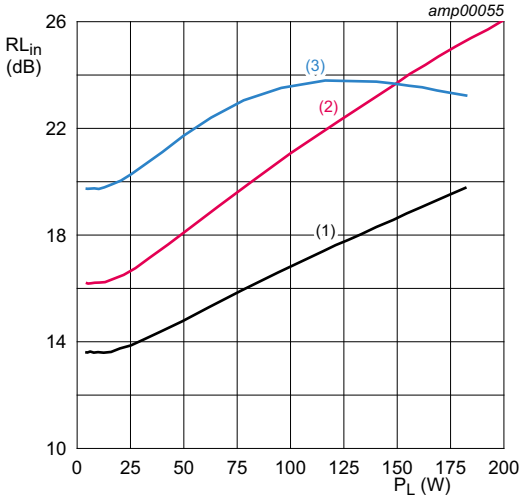

$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 10. Adjacent channel power ratio (5 MHz) as a function of output power; typical values**




$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) f = 1805 MHz

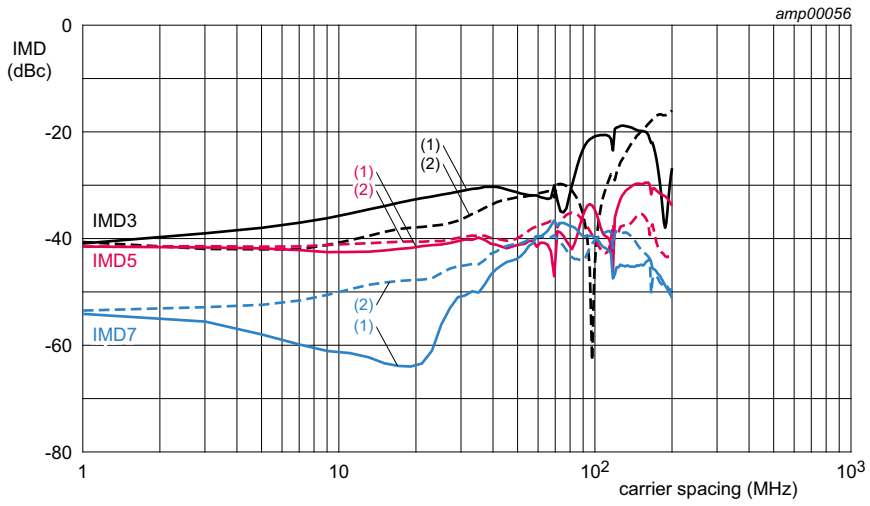
(2) f = 1842.5 MHz

(3) f = 1880 MHz

**Fig 11. Input return loss as a function of output power; typical values**


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### 7.5.4 2-Tone VBW




$V_{DS}$ = 28 V; $I_{Dq}$ = 1000 mA; $V_{GS(amp)peak}$ = 0.75 V.

(1) IMD low

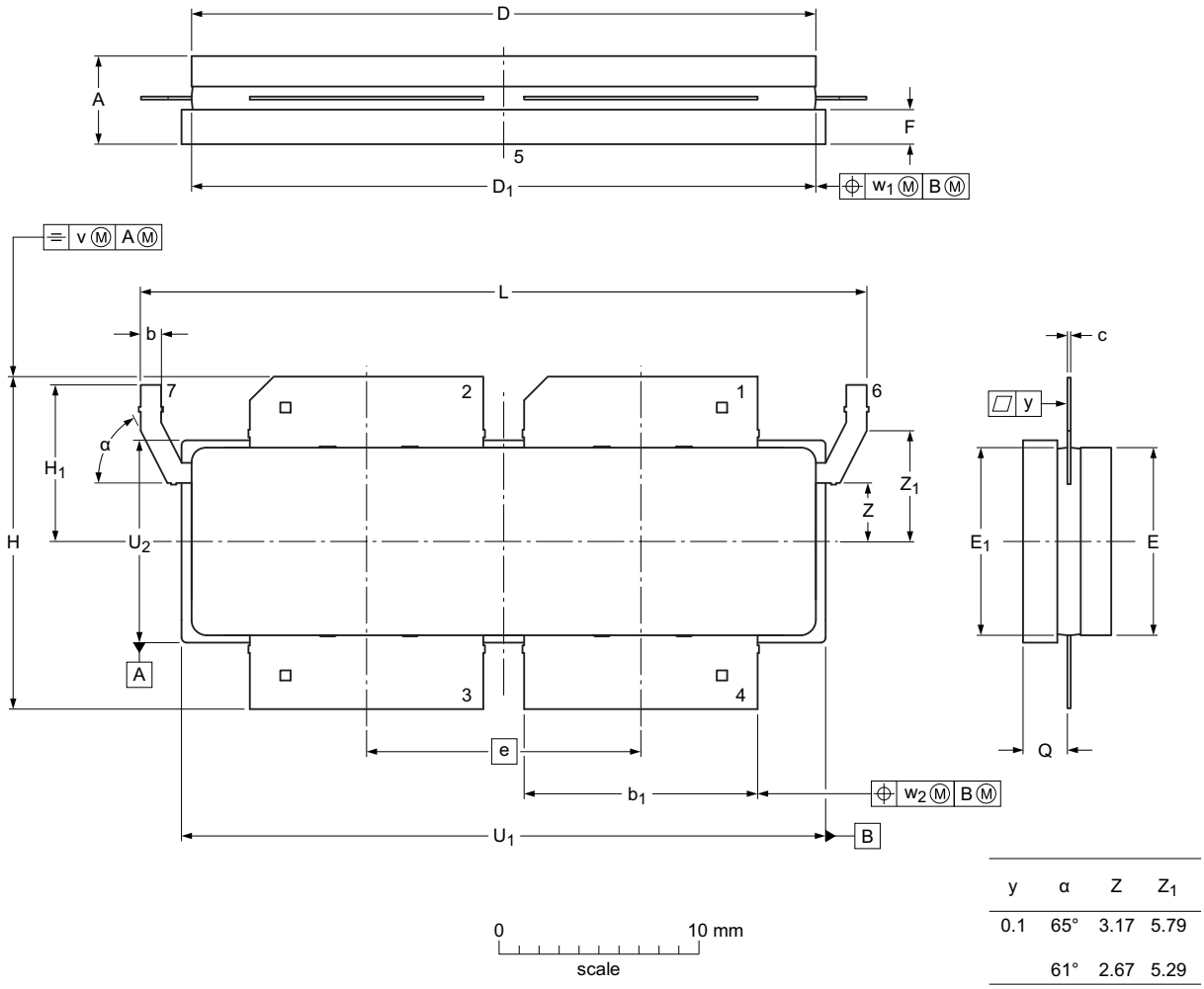
(2) IMD high

**Fig 12. VBW capability**


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# 8. Package outline

**Air cavity plastic earless flanged package; 6 leads** **SOT1258-4**




| y | α | Z | $Z_1$ |
|---|---|---|---|
| 0.1 | 65° | 3.17 | 5.79 |
| | 61° | 2.67 | 5.29 |

Dimensions

| Unit | | A | b | $b_1$ | c | D | $D_1$ | E | $E_1$ | e | L | F | H | $H_1$ | Q[1] | $U_1$ | $U_2$ | v | $w_1$ | $w_2$ |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| mm | max | 4.52 | 1.12 | 11.78 | 0.18 | 31.44 | 31.34 | 9.60 | 9.50 | 13.72 | 36.42 | 1.73 | 16.71 | 8.12 | 2.25 | 32.33 | 10.23 | 0.5 | 0.5 | 0.5 |
| | nom | | | | | | | | | | | | | | | | | | | |
| | min | 4.12 | 0.91 | 11.58 | 0.13 | 31.04 | 31.14 | 9.20 | 9.30 | | 36.22 | 1.53 | 16.51 | 7.62 | 2.03 | 32.13 | 10.03 | | | |

Note
1. Dimension Q is measured 0.1 mm away from the flange.
2. Ringframe and/or ringframe glue shall not overhang at the side of the flange.

*sot1258-4_po*

| Outline version | References | | | | European projection | Issue date |
|---|---|---|---|---|---|---|
| | IEC | JEDEC | JEITA | | | |
| SOT1258-4 | | | | | | 17-08-31 |

**Fig 13. Package outline SOT1258-4**


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# 9. Handling information

**CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

**Table 16. ESD sensitivity**

| ESD model | Class |
|---|---|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C2A [1] |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001 | 2 [2] |

[1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

# 10. Abbreviations

**Table 17. Abbreviations**

| Acronym | Description |
|---|---|
| 3GPP | 3rd Generation Partnership Project |
| AM | Amplitude Modulation |
| CCDF | Complementary Cumulative Distribution Function |
| CW | Continuous Wave |
| DPCH | Dedicated Physical CHannel |
| ESD | ElectroStatic Discharge |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor |
| MTF | Median Time to Failure |
| OBO | Output Back Off |
| PAR | Peak-to-Average Ratio |
| PM | Phase Modulation |
| SMD | Surface Mounted Device |
| VBW | Video BandWidth |
| VSWR | Voltage Standing Wave Ratio |
| W-CDMA | Wideband Code Division Multiple Access |


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# 11. Revision history

**Table 18. Revision history**

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---|---|---|---|---|
| BLC9G20XS-550AVT v.3 | 20171124 | Product data sheet | - | BLC9G20XS-550AVT v.2 |
| Modifications: | • Table 2 on page 2: changed simplified version drawing SOT1258-7 to SOT1258-4<br>• Table 3 on page 2: changed version SOT1258-7 to SOT1258-4<br>• Figure 13 on page 12: changed package outline drawing SOT1258-7 to SOT1258-4 | | | |
| BLC9G20XS-550AVT v.2 | 20161202 | Product data sheet | - | BLC9G20XS-550AVT v.1 |
| BLC9G20XS-550AVT v.1 | 20160513 | Product data sheet | - | - |


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# 12. Legal information

## 12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|---|---|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

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